NSN 5961-01-189-0610

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-189-0610 **Inclosure Material:** Ceramic **Overall Length:** 0.250 inches **Terminal Length:** 0.700 inches **Overall Diameter:** 0.085 inches **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 forward voltage, dc **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 20.00 amperes peak forward surge current nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No